

# Octal D-type flip-flop; positive-edge trigger (3-State)

## 74ABT374

### FEATURES

- 8-bit positive edge triggered register
- 3-State output buffers
- Output capability: +64mA/-32mA
- Latch-up protection exceeds 500mA per Jedec JC40.2 Std 17
- ESD protection exceeds 2000 V per MIL STD 883 Method 3015 and 200 V per Machine Model
- Power-up 3-State
- Power-up reset

### DESCRIPTION

The 74ABT374 high-performance BiCMOS device combines low static and dynamic power dissipation with high speed and high output drive.

The 74ABT374 is an 8-bit, edge triggered register coupled to eight 3-State output buffers. The two sections of the device are controlled independently by the clock (CP) and Output Enable (OE) control gates.

The register is fully edge triggered. The state of each D input, one set-up time before the Low-to-High clock transition, is transferred to the corresponding flip-flop's Q output.

The 3-State output buffers are designed to drive heavily loaded 3-State buses, MOS memories, or MOS microprocessors. The active-Low Output Enable (OE) controls all eight 3-State buffers independent of the clock operation.

(continued)

### QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS $T_{amb} = 25^{\circ}\text{C}; \text{GND} = 0\text{V}$	TYPICAL	UNIT
$t_{PLH}$ $t_{PHL}$	Propagation delay CP to Qn	$C_L = 50\text{pF}; V_{CC} = 5\text{V}$	4.8	ns
$C_{IN}$	Input capacitance	$V_I = 0\text{V}$ or $V_{CC}$	4	pF
$C_{OUT}$	Output capacitance	Outputs disabled; $V_O = 0\text{V}$ or $V_{CC}$	7	pF
$I_{CCZ}$	Total supply current	Outputs disabled; $V_{CC} = 5.5\text{V}$	500	nA

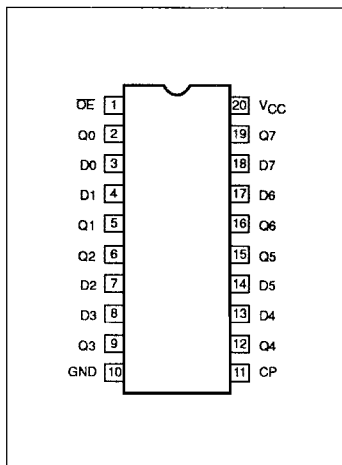
### ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	ORDER CODE	DRAWING NUMBER
20-pin plastic DIP	-40°C to +85°C	74ABT374N	0408B
20-pin plastic SOL	-40°C to +85°C	74ABT374D	0172D
20-pin plastic SSOP	-40°C to +85°C	74ABT374DB	1640A

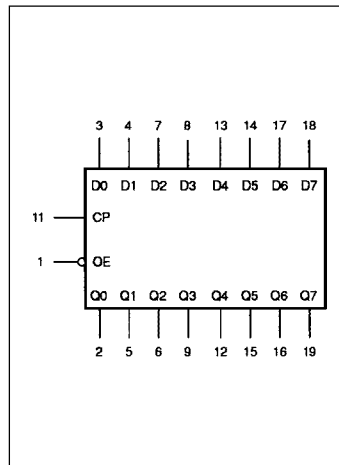
### PIN DESCRIPTION

PIN NUMBER	SYMBOL	FUNCTION
1	OE	Output enable input (active-Low)
3, 4, 7, 8, 13, 14, 17, 18	D0-D7	Data inputs
2, 5, 6, 9, 12, 15, 16, 19	Q0-Q7	Data outputs
11	CP	Clock pulse input (active rising edge)
10	GND	Ground (0V)
20	$V_{CC}$	Positive supply voltage

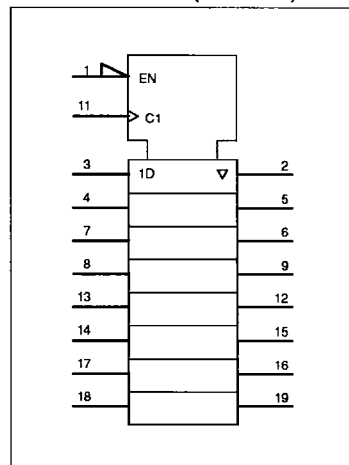
### PIN CONFIGURATION



### LOGIC SYMBOL



### LOGIC SYMBOL (IEEE/IEC)



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74ABT374

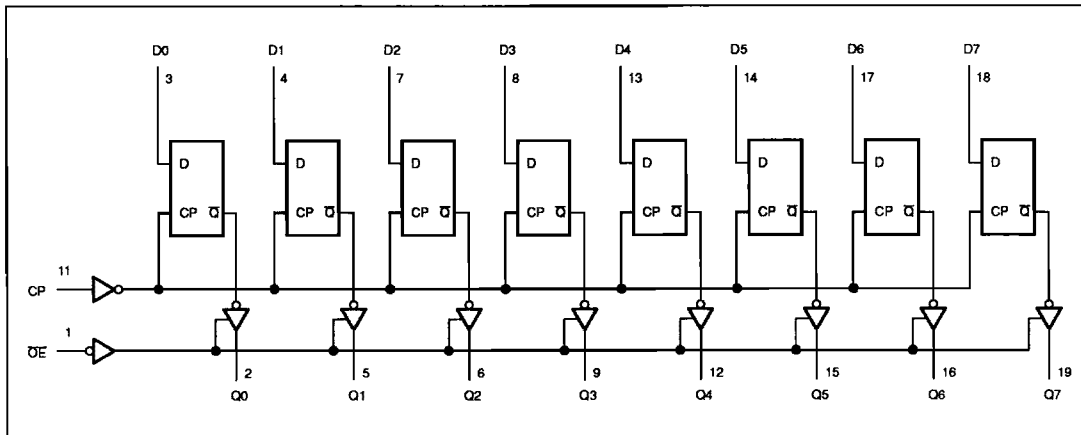
When  $\overline{OE}$  is Low, the stored data appears at the outputs. When  $\overline{OE}$  is High, the outputs are in the High-impedance "OFF" state, which means they will neither drive nor load the bus.

### FUNCTION TABLE

INPUTS			INTERNAL REGISTER	OUTPUTS	OPERATING MODE
$\overline{OE}$	CP	Dn		Q0 - Q7	
L L	$\uparrow$ $\uparrow$	l h	L H	L H	Latch and read register
L	$\nabla$	X	NC	NC	Hold
H H	$\nabla$ $\uparrow$	X Dn	NC Dn	Z Z	Disable outputs

- H = High voltage level
- h = High voltage level one set-up time prior to the Low-to-High clock transition
- L = Low voltage level
- l = Low voltage level one set-up time prior to the Low-to-High clock transition
- NC= No change
- X = Don't care
- Z = High impedance "off" state
- $\uparrow$  = Low-to-High clock transition
- $\nabla$  = not a Low-to-High clock transition

### LOGIC DIAGRAM



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74ABT374

## ABSOLUTE MAXIMUM RATINGS<sup>1, 2</sup>

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
$V_{CC}$	DC supply voltage		-0.5 to +7.0	V
$I_{IK}$	DC input diode current	$V_I < 0$	-18	mA
$V_I$	DC input voltage <sup>3</sup>		-1.2 to +7.0	V
$I_{OK}$	DC output diode current	$V_O < 0$	-50	mA
$V_{OUT}$	DC output voltage <sup>3</sup>	output in Off or High state	-0.5 to +5.5	V
$I_{OUT}$	DC output current	output in Low state	128	mA
$T_{stg}$	Storage temperature range		-65 to 150	°C

### NOTES:

- Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.
- The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

## RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIMITS		UNIT
		Min	Max	
$V_{CC}$	DC supply voltage	4.5	5.5	V
$V_I$	Input voltage	0	$V_{CC}$	V
$V_{IH}$	High-level input voltage	2.0		V
$V_{IL}$	Low-level input voltage		0.8	V
$I_{OH}$	High-level output current		-32	mA
$I_{OL}$	Low-level output current		64	mA
$\Delta t/\Delta v$	Input transition rise or fall rate	0	5	ns/V
$T_{amb}$	Operating free-air temperature range	-40	+85	°C

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74ABT374

## DC ELECTRICAL CHARACTERISTICS

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS					UNIT
			T <sub>amb</sub> = +25°C			T <sub>amb</sub> = -40°C to +85°C		
			Min	Typ	Max	Min	Max	
V <sub>IK</sub>	Input clamp voltage	V <sub>CC</sub> = 4.5V; I <sub>IK</sub> = -18mA		-0.9	-1.2		-1.2	V
V <sub>OH</sub>	High-level output voltage	V <sub>CC</sub> = 4.5V; I <sub>OH</sub> = -3mA; V <sub>I</sub> = V <sub>IL</sub> or V <sub>IH</sub>	2.5	2.9		2.5		V
		V <sub>CC</sub> = 5.0V; I <sub>OH</sub> = -3mA; V <sub>I</sub> = V <sub>IL</sub> or V <sub>IH</sub>	3.0	3.4		3.0		V
		V <sub>CC</sub> = 4.5V; I <sub>OH</sub> = -32mA; V <sub>I</sub> = V <sub>IL</sub> or V <sub>IH</sub>	2.0	2.4		2.0		V
V <sub>OL</sub>	Low-level output voltage	V <sub>CC</sub> = 4.5V; I <sub>OL</sub> = 64mA; V <sub>I</sub> = V <sub>IL</sub> or V <sub>IH</sub>		0.42	0.55		0.55	V
V <sub>RST</sub>	Power-up output low voltage <sup>3</sup>	V <sub>CC</sub> = 5.5V; I <sub>O</sub> = 1mA; V <sub>I</sub> = GND or V <sub>CC</sub>		0.13	0.55		0.55	V
I <sub>I</sub>	Input leakage current	V <sub>CC</sub> = 5.5V; V <sub>I</sub> = GND or 5.5V		±0.01	±1.0		±1.0	μA
I <sub>OFF</sub>	Power-off leakage current	V <sub>CC</sub> = 0.0V; V <sub>O</sub> or V <sub>I</sub> ≤ 4.5V		±5.0	±100		±100	μA
I <sub>PU</sub> /I <sub>PD</sub>	Power-up/down 3-State output current	V <sub>CC</sub> = 0.0V; I <sub>O</sub> = 1mA; V <sub>I</sub> = GND or V <sub>CC</sub> ; V <sub>OE</sub> = V <sub>CC</sub>		±5.0	±50		±50	μA
I <sub>OZH</sub>	3-State output High current	V <sub>CC</sub> = 5.5V; V <sub>O</sub> = 2.7V; V <sub>I</sub> = V <sub>IL</sub> or V <sub>IH</sub>		5.0	50		50	μA
I <sub>OZL</sub>	3-State output Low current	V <sub>CC</sub> = 5.5V; V <sub>O</sub> = 0.5V; V <sub>I</sub> = V <sub>IL</sub> or V <sub>IH</sub>		-5.0	-50		-50	μA
I <sub>CEX</sub>	Output High leakage current	V <sub>CC</sub> = 5.5V; V <sub>O</sub> = 0.5V; V <sub>I</sub> = GND or V <sub>CC</sub>		5.0	50		50	μA
I <sub>O</sub>	Output current <sup>1</sup>	V <sub>CC</sub> = 5.5V; V <sub>O</sub> = 2.5V	-50	-100	-180	-50	-180	mA
I <sub>CCH</sub>	Quiescent supply current	V <sub>CC</sub> = 5.5V; Outputs High, V <sub>I</sub> = GND or V <sub>CC</sub>		0.5	50		50	μA
I <sub>CCL</sub>		V <sub>CC</sub> = 5.5V; Outputs Low, V <sub>I</sub> = GND or V <sub>CC</sub>		24	30		30	mA
I <sub>CCZ</sub>		V <sub>CC</sub> = 5.5V; Outputs 3-State; V <sub>I</sub> = GND or V <sub>CC</sub>		0.5	50		50	μA
ΔI <sub>CC</sub>	Additional supply current per input pin <sup>2</sup>	V <sub>CC</sub> = 5.5V; one input at 3.4V, other inputs at V <sub>CC</sub> or GND		0.5	1.5		1.5	mA

### NOTES:

- Not more than one output should be tested at a time, and the duration of the test should not exceed one second.
- This is the increase in supply current for each input at 3.4V.
- For valid test results, data must not be loaded into the flip-flops (or latches) after applying the power.

## AC CHARACTERISTICS

GND = 0V, t<sub>R</sub> = t<sub>F</sub> = 2.5ns, C<sub>L</sub> = 50pF, R<sub>L</sub> = 500Ω

SYMBOL	PARAMETER	WAVEFORM	LIMITS					UNIT
			T <sub>amb</sub> = +25°C V <sub>CC</sub> = +5.0V			T <sub>amb</sub> = -40 to +85°C V <sub>CC</sub> = +5.0V ±0.5V		
			Min	Typ	Min	Min	Max	
f <sub>MAX</sub>	Maximum clock frequency	1	150	200		150		ns
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay CP to Qn	1	2.2	3.9	5.7	2.2	6.2	ns
			3.1	4.8	6.6	3.1	7.1	
t <sub>PZH</sub> t <sub>PLZ</sub>	Output enable time to High and Low level	3 4	1.2	3.2	4.7	1.2	5.2	ns
			2.7	4.7	6.2	2.7	6.7	
t <sub>PHZ</sub> t <sub>PLZ</sub>	Output disable time from High and Low level	3 4	2.5	4.9	6.0	2.5	6.5	ns
			2.0	4.0	6.0	2.0	6.5	

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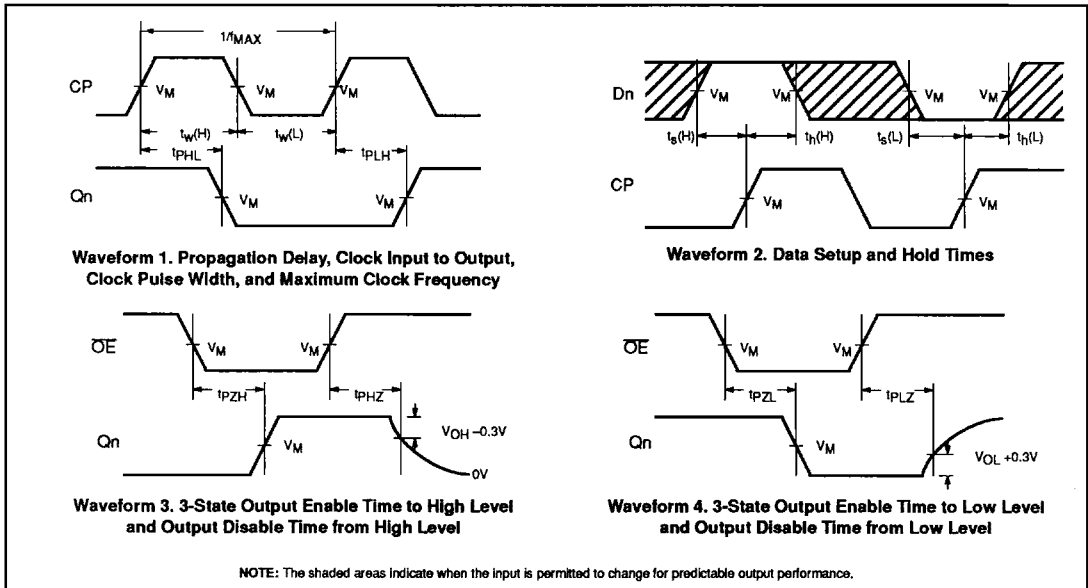
## AC SETUP REQUIREMENTS

GND = 0V,  $t_R = t_F = 2.5\text{ns}$ ,  $C_L = 50\text{pF}$ ,  $R_L = 500\Omega$

SYMBOL	PARAMETER	WAVEFORM	LIMITS			UNIT
			$T_{\text{amb}} = +25^\circ\text{C}$ $V_{\text{CC}} = +5.0\text{V}$		$T_{\text{amb}} = -40$ to $+85^\circ\text{C}$ $V_{\text{CC}} = +5.0\text{V} \pm 0.5\text{V}$	
			Min	Typ	Min	
$t_s(\text{H})$ $t_s(\text{L})$	Setup time, High or Low Dn to CP	2	1.0 1.9	0.0 0.3	1.0 1.9	ns
$t_h(\text{H})$ $t_h(\text{L})$	Hold time, High or Low Dn to CP	2	1.0 1.0	-0.1 0.3	1.0 1.0	ns
$t_w(\text{H})$ $t_w(\text{L})$	CP pulse width High or Low	1	3.3 3.3	2.0 1.3	3.3 3.3	ns

## AC WAVEFORMS

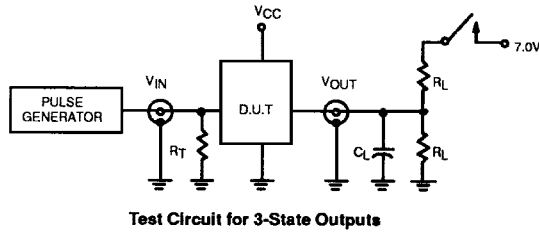
$V_M = 1.5\text{V}$ ,  $V_{\text{IN}} = \text{GND to } 3.0\text{V}$



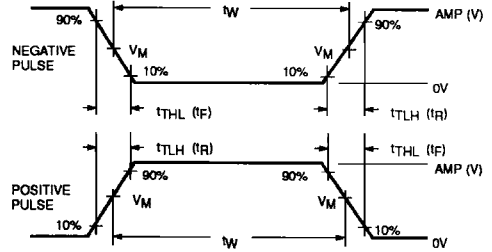
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74ABT374

## TEST CIRCUIT AND WAVEFORM



Test Circuit for 3-State Outputs



$V_M = 1.5V$   
Input Pulse Definition

### SWITCH POSITION

TEST	SWITCH
$t_{PLZ}$	closed
$t_{PZL}$	closed
All other	open

### DEFINITIONS

- $R_L$  = Load resistor; see AC CHARACTERISTICS for value.
- $C_L$  = Load capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.
- $R_T$  = Termination resistance should be equal to  $Z_{OUT}$  of pulse generators.

FAMILY	INPUT PULSE REQUIREMENTS				
	Amplitude	Rep. Rate	$t_W$	$t_R$	$t_F$
74ABT	3.0V	1MHz	500ns	2.5ns	2.5ns